## US1J

# SURFACE MOUNT ULTRAFAST RECTIFIER

VOLTAGE: 600V CURRENT: 1.0A



### **FEATURE**

Ideal for surface mount pick and place application

Low profile package

Built-in strain relief

High surge capability

High temperature soldering guaranteed

260 °C/10sec/at terminals

Glass passivated chip

Ultrafast recovery time for high efficiency

### **MECHANICAL DATA**

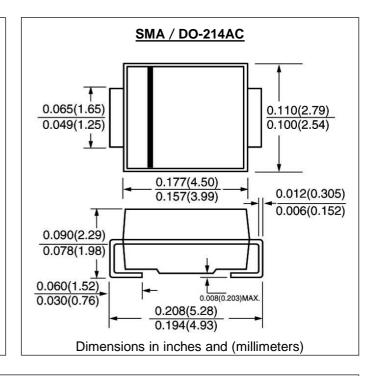
Terminal: Solder plated, solderable per MIL-STD-750,

Method 2026

Case: JEDEC DO-214AC molded plastic over glass

passivated chip

Polarity: Color band denotes cathode



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

	SYMBOL	US1J	units
Maximum Recurrent Peak Reverse Voltage	Vrrm	600	V
Maximum RMS Voltage	Vrms	280	V
Maximum DC blocking Voltage	Vdc	600	V
Maximum Average Forward Rectified Current 3/8″ lead length at T <sub>L</sub> =110°C	If(av)	1.0	А
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load	Ifsm	30.0	А
Maximum Forward Voltage at rated forward current	Vf	1.7	V
Maximum DC Reverse Current Ta =25°C	lr	10.0	μ <b>А</b>
at rated DC blocking voltage Ta =100°C		100.0	μ <b>A</b>
Maximum Reverse Recovery Time (Note1)	Trr	75	nS
Typical Junction Capacitance (Note 2)	Cj	18.0	pF
Typical Thermal Resistance (Note 3)	R(jl)	30.0	°C/W
Storage and Operating Junction Temperature	Tstg, Tj	-50 to +150	$^{\circ}$ C

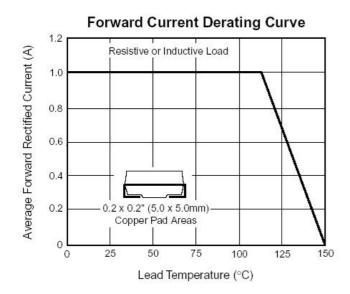
#### Note:

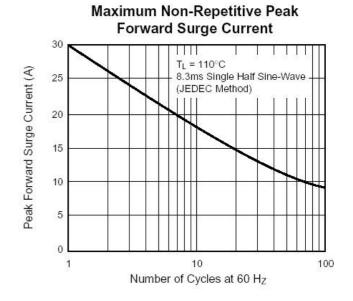
- 1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A
- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
- 3. Thermal Resistance from Junction to terminal mounted on 5×5mm copper pad area1

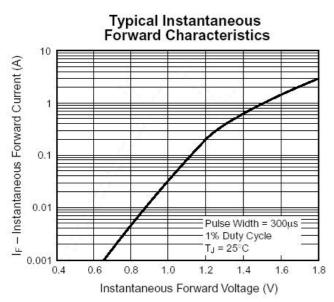
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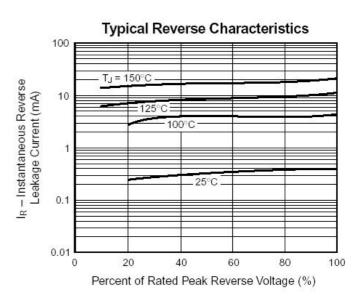
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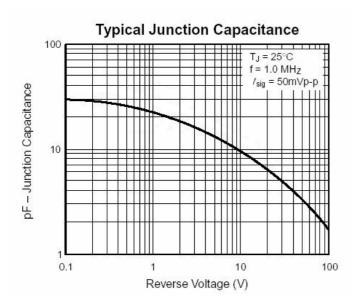
#### **RATINGS AND CHARACTERISTIC CURVES US1J**

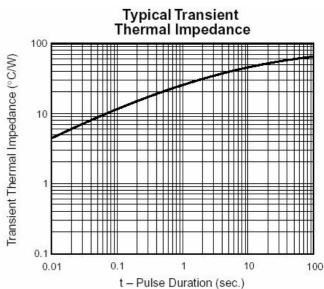












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